OLLE		Docket Number (Optional)	Application Number		
INFORMATION DISCLOSUDE CITATION		FIS920020166US1	10/604,487		
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OIPE		Docket Number (Optional) FIS920020166US1	Application Number 10/604,487	
INFORMATION DISCLOSURE CITATION		Applicant(s) Hendrik F. Hamann et al.	10/004,40/	
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not considered. Include copy of this form with next communication to applicant.

		Docket Number (Optional)	Andread N. A.	
OIPE		FIS920020166US1	Application Number 10/604,487	
INFO	MATION DISCLOSURE CITATION	Applicant(s)	10/004,487	
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P09B/REV04

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention

SYSTEM AND METHODS OF ALTERING A VERY SMALL SURFACE AREA

Application Number:

10/604,487

Confirmation Number:

First Named Applicant:

Hendrik Hamann

Attorney Docket Number:

FIS920020166US1

Art Unit:

1763

Examiner:

MAUREEN G. ARANCIBIA

Search string:

(4550257 or 4925139 or 5865978 or 6002471 or 4880496 or 6078055).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

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Signature

Examiner Name	Date
Maureen Paranchin	09/13/2004